

# P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

# DESCRIPTION

The  $\mu$ PA1814 is a switching device which can be driven directly by a 4 V power source.

The  $\mu$ PA1814 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

## **FEATURES**

- Can be driven by a 4 V power source
- · Low on-state resistance  $R_{DS(on)1} = 16 \text{ m}\Omega \text{ MAX.} (V_{GS} = -10 \text{ V}, \text{ ID} = -3.5 \text{ A})$  $R_{DS(on)2} = 24 \text{ m}\Omega \text{ MAX.} (V_{GS} = -4.5 \text{ V}, \text{ ID} = -3.5 \text{ A})$  $R_{DS(on)3} = 27 \text{ m}\Omega \text{ MAX.} (V_{GS} = -4.0 \text{ V}, \text{ ID} = -3.5 \text{ A})$
- Built-in G-S protection diode against ESD

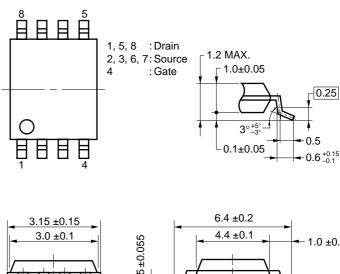
### **ORDERING INFORMATION**

PART NUMBER	PACKAGE
μPA1814GR-9JG	Power TSSOP8

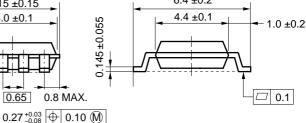
## ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

Drain to Source Voltage	VDSS	-30	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	D(DC)	±7.0	А
Drain Current (pulse) <sup>Note1</sup>	D(pulse)	±28	А
Total Power Dissipation Note2	P⊤	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

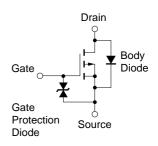
# PACKAGE DRAWING (Unit : mm)



0.65 0.8 MAX



### **EQUIVALENT CIRCUIT**



**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

- 2. Mounted on ceramic substrate of 5000 mm<sup>2</sup> x 1.1 mm
- Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

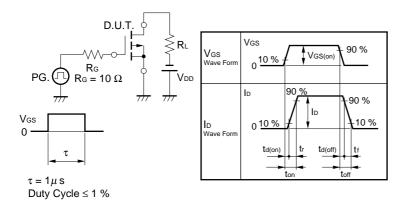
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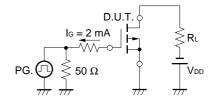
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -30 V, V_{GS} = 0 V$			-10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = -10 V$ , $I_{D} = -1 mA$	-1.0	-1.7	-2.5	V
Forward Transfer Admittance	y <sub>fs</sub>	$V_{DS} = -10 V$ , $I_D = -3.5 A$	3	14		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 V$ , $I_D = -3.5 A$		12	16	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, \text{ Id} = -3.5 \text{ A}$		18	24	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, \text{ Id} = -3.5 \text{ A}$		20	27	mΩ
Input Capacitance	Ciss	$V_{DS} = -10 V$		2180		pF
Output Capacitance	Coss	Vgs = 0 V		658		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		303		pF
Turn-on Delay Time	td(on)	$V_{DD} = -15 V$		30		ns
Rise Time	tr	ID = -3.5 A		140		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = -10 V$		97		ns
Fall Time	tr	Rg = 10 Ω		86		ns
Total Gate Charge	QG	V <sub>DS</sub> = -24 V		38		nC
Gate to Source Charge	QGS	ID = -7.0 A		5.9		nC
Gate to Drain Charge	Qgd	V <sub>GS</sub> = -10 V		8.5		nC
Diode Forward Voltage	VF(S-D)	IF = 7.0 A, VGs = 0 V		0.79		V

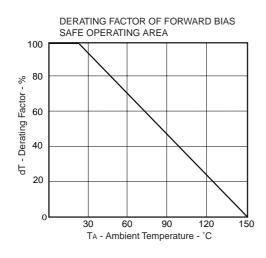
# **TEST CIRCUIT 1 SWITCHING TIME**

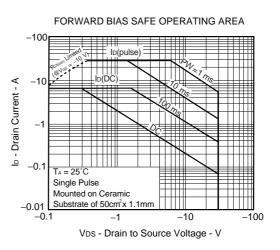


# TEST CIRCUIT 2 GATE CHARGE

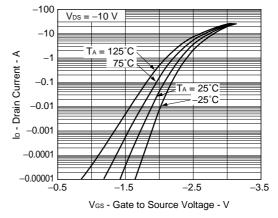


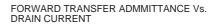
## \* TYPICAL CHARACTERISTICS (TA = 25 °C)

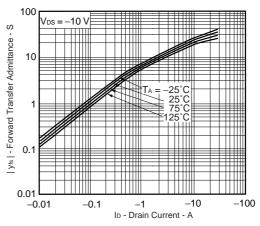


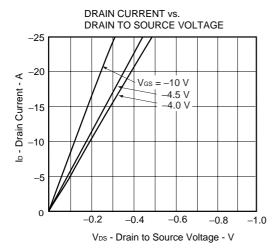


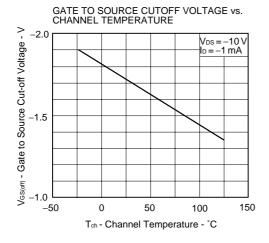
FORWARD TRANSFER CHARACTERISTICS



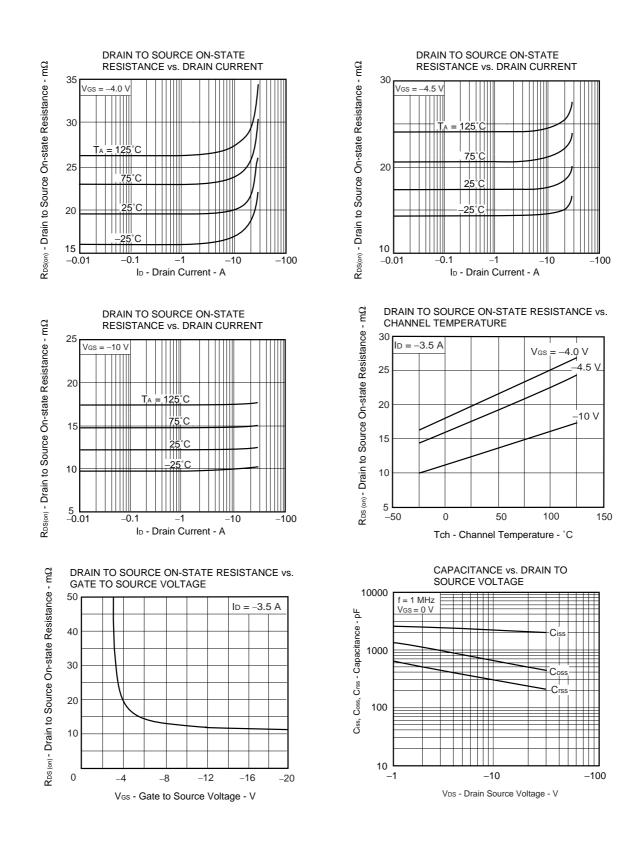




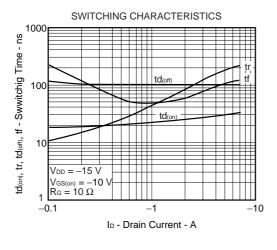


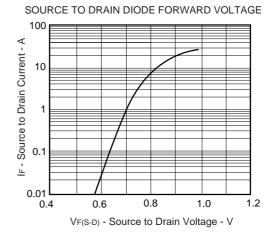


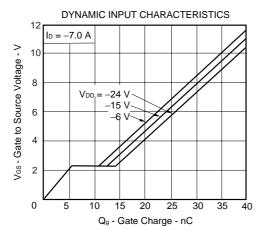
Data Sheet D13804EJ1V0DS00



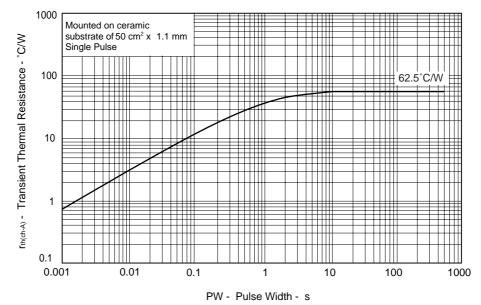
Data Sheet D13804EJ1V0DS00











Data Sheet D13804EJ1V0DS00

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